

AgGaSe2 crystals

AGSe AgGaSe2 crystals have band edges at 0.73 and 18 μm . Its useful transmission range (0.9–16 μm) and wide phase matching capability provide excellent potential for OPO applications when pumped by a variety of different lasers. Tuning within 2.5–12 μm has been obtained when pumping by Ho:YLF laser at 2.05 μm ; as well as non-critical phase matching (NCPM) operation within 1.9–5.5 μm when pumping at 1.4–1.55 μm . AgGaSe2 (AgGaSe2) has been demonstrated to be an efficient frequency doubling crystal for infrared CO2 lasers radiation.



Dimensions:

Standard cross sections are 8x 8mm, 5 x 5mm, Crystal length range from 1 to 30 mm. Custom sizes are also available on request.

AgGaSe₂ crystals



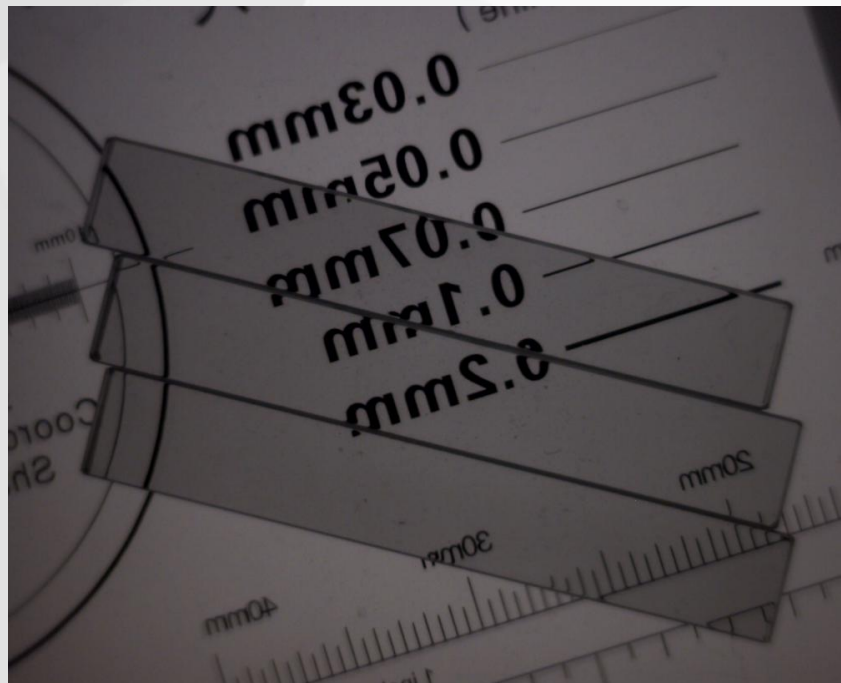
Applications:

- Generation second harmonics on CO and CO₂ - lasers
- Optical parametric oscillator
- Different frequency generator to middle infrared regions up to 18 μm .
- Frequency mixing in the middle IR region

Basic properties

Crystal Structure	Tetragonal
Cell Parameters	$a=5.992 \text{ \AA}$, $c=10.886 \text{ \AA}$
Melting Point	851 °C
Density	5.700 g/cm ³
Mohs Hardness	3-3.5
Absorption Coefficient	$<0.05 \text{ cm}^{-1} @ 1.064 \mu\text{m}$ $<0.02 \text{ cm}^{-1} @ 10.6 \mu\text{m}$
Relative Dielectric Constant @ 25 MHz	$\epsilon_{11s}=10.5$ $\epsilon_{11t}=12.0$
Thermal Expansion Coefficient	$ C: -8.1 \times 10^{-6} / ^\circ\text{C}$ $\perp C: +19.8 \times 10^{-6} / ^\circ\text{C}$
Thermal Conductivity	1.0 W/M/°C

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Internal quality under IR camera

Linear Optical Properties		
Transparency Range	0.73-18.0 um	
Refractive Indices@ 1.064 um@ 5.300 um@ 10.60 um	no2.70102.61342.5912	ne2.67922.58082.5579
Thermo-Optic Coefficient	dno/dt=15.0 x 10-5/°C dne/dt=15.0 x 10-5/°C	
Sellmeier Equations(λ in um)	no2=4.6453+2.2057/(1-0.1879/λ2)+1.8577/(1-1600/λ2)ne2=5.2912+1.3970/(1-0.2845/λ2)+1.9282/(1-16007/λ2)	
Nonlinear Optical Properties		
NLO Coefficients @ 10.6 um	d36=d24=d15=39.5 pm/V	
Linear Electro-optic Coefficients	Y41T=4.5 pm/VY63T=3.9 pm/V	
Damage Threshold @ ~ 10 ns, 1.064 um	20-30 MW/cm2(surface)	

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Technical Properties

Dimension tolerance	(W +/-0.1 mm) x (H +/-0.1 mm) x (L + 1 mm/-0.5 mm)
Clear aperture	> 90% central area
Surface quality	30-20 before coating 60-40 after coating
Flatness	$\lambda/8$ @ 633 nm for T>=1 mm
Surface Quality	Scratch/dig 60-40 after coating
Parallelism	better than 30 arc seconds
Perpendicularity	10 arc minutes
Orientation accuracy	<30''

